



**THE DATASHEET OF
BAT1704WH6327XTSA1**



BAT17-04W

Series silicon RF Schottky diode pair



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Technical documents



Simulation



Support

Product description

These Infineon RF Schottky diodes are silicon low barrier N-type devices with an integrated guard ring on-chip for overvoltage protection. Their low barrier height, small forward voltage and low junction capacitance, make BAT17-04W a suitable choice for mixer and detector applications at frequencies as high as 6 GHz.



Feature list

- Low inductance $L_s = 1.4$ nH (typical)
- Low capacitance $C = 0.61$ pF (typical) at frequency $f = 1$ MHz
- Industry standard SOT323-3 package (2.1 mm x 2 mm x 0.9 mm)
- Pb-free, RoHS compliant and halogen free

Product validation

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22.

Potential applications

For mixers and detectors in:

- Wearables
- Smart metering
- Telematic systems
- Set top boxes

Device information

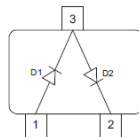


Table 1 Part information

Product name / Ordering code	Package	Pin configuration	Marking	Pieces / Reel
BAT17-04W / BAT1704WH6327XTSA1	SOT323-3	Series pair	54s	3 k

Attention: ESD (Electrostatic discharge) sensitive device, observe handling precautions!

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1 Absolute maximum ratings

Table 2 Absolute maximum ratings at $T_A = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Values		Unit	Note or test condition
		Min.	Max.		
Diode reverse voltage	V_R	–	4	V	
Forward current	I_F	–	130	mA	
Total power dissipation	P_{TOT}	–	150	mW	$T_S \leq 100\text{ °C}$ ¹⁾
Junction temperature	T_J	–	150	°C	
Operating temperature	T_{OP}	-55	125		
Storage temperature	T_{STG}	-55	150		

Attention: *Stresses above the maximum values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Exceeding only one of these values may cause irreversible damage to the component.*

¹ T_S is the soldering point temperature.

Electrical performance in test fixture

2 Electrical performance in test fixture

2.1 Electrical characteristics

Table 3 Electrical characteristics at $T_A = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Breakdown voltage	V_{BR}	4	–	–	V	$I_R = 10\ \mu\text{A}$
Reverse current	I_R	–	–	0.25	μA	$V_R = 3\ \text{V}$
		–	–	1.25		$V_R = 3\ \text{V}, T_A = 60\text{ °C}$ ¹⁾
		–	–	10		$V_R = 4\ \text{V}$
Forward voltage	V_F	0.2	0.27	0.35	V	$I_F = 0.1\ \text{mA}$
		0.25	0.34	0.45		$I_F = 1\ \text{mA}$
		0.35	0.42	0.60		$I_F = 10\ \text{mA}$
Forward voltage matching	ΔV_F	–	–	20	mV	$I_F = 1\ \text{mA}$ ²⁾
Differential forward resistance	R_F	–	8	15	Ω	$I_F = 5\ \text{mA}$
Capacitance	C	0.4	0.61	0.7	pF	$V_R = 0\ \text{V}, f = 1\ \text{MHz}$
Inductance	L_S	–	1.4	–	nH	

¹ Parameter is not subject to production test, min/max values are specified by design.

² ΔV_F is the difference between lowest and highest V_F in a multiple diode component.

Electrical performance in test fixture

2.2 Characteristic curves

At $T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified

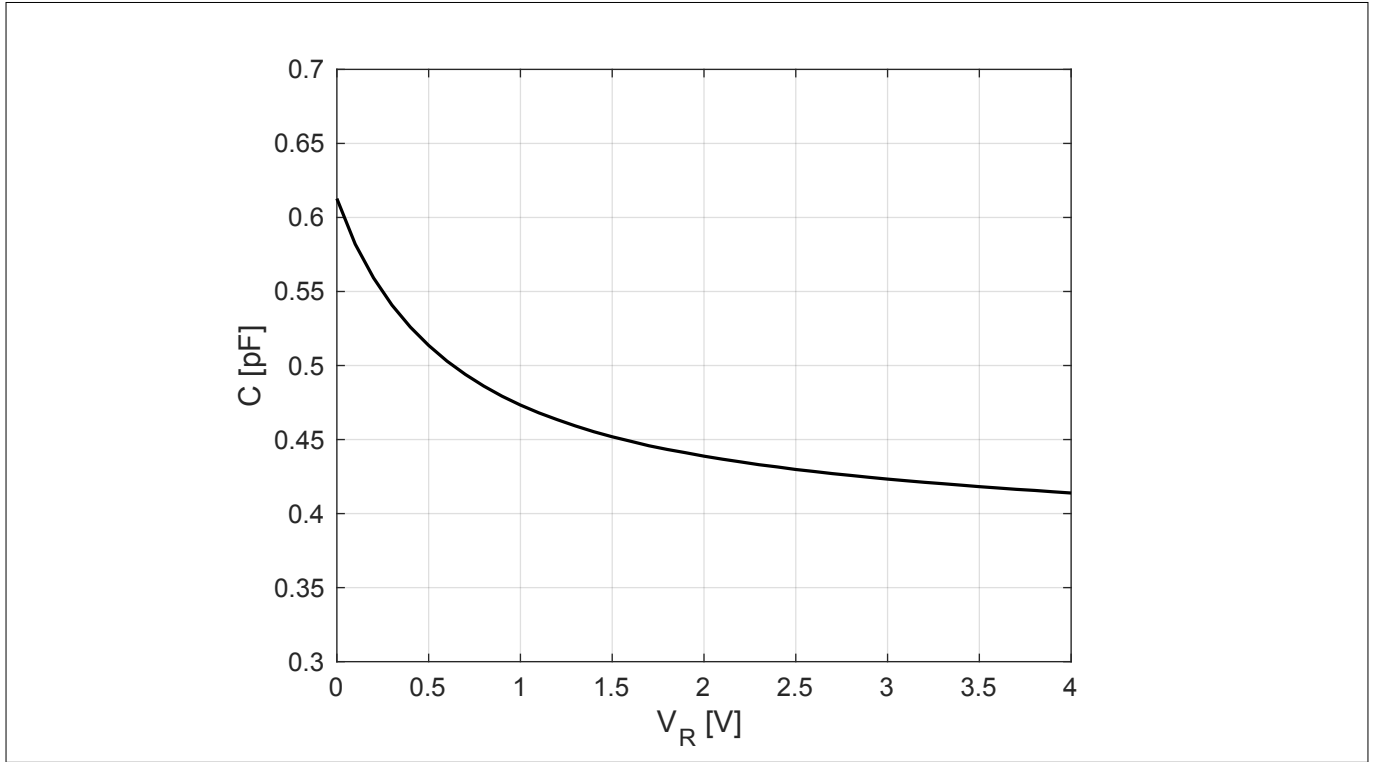


Figure 1 Capacitance C vs. reverse voltage V_R at frequency $f = 1\text{ MHz}$

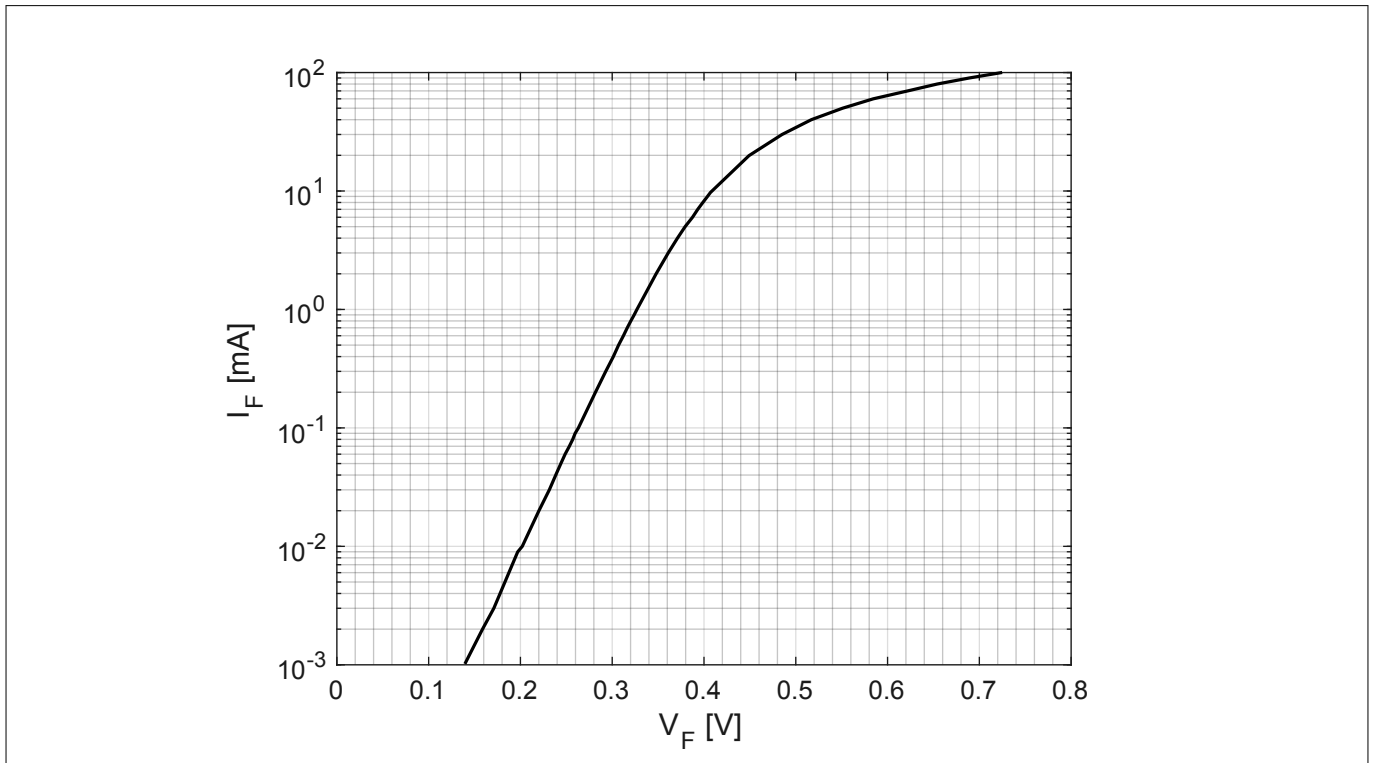


Figure 2 Forward current I_F vs. forward voltage V_F

Electrical performance in test fixture

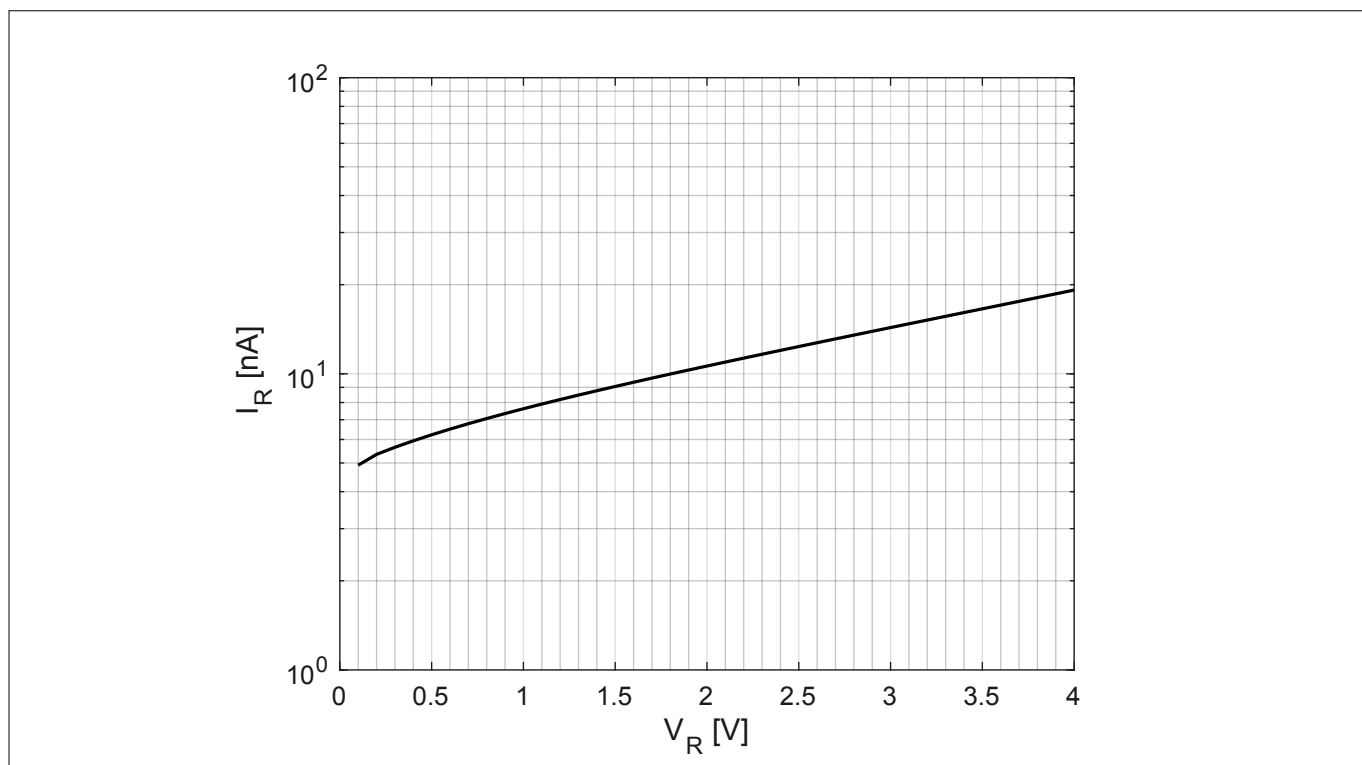


Figure 3 Reverse current I_R vs. reverse voltage V_R

Note: The curves shown in this chapter have been generated using typical devices but shall not be understood as a guarantee that all devices have identical characteristic curves.

Thermal characteristics

3 Thermal characteristics

Table 4 Thermal resistance

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Thermal resistance (junction - soldering point)	R_{thJS}	-	330	-	K/W	$T_S = 100\text{ °C}$ ¹⁾

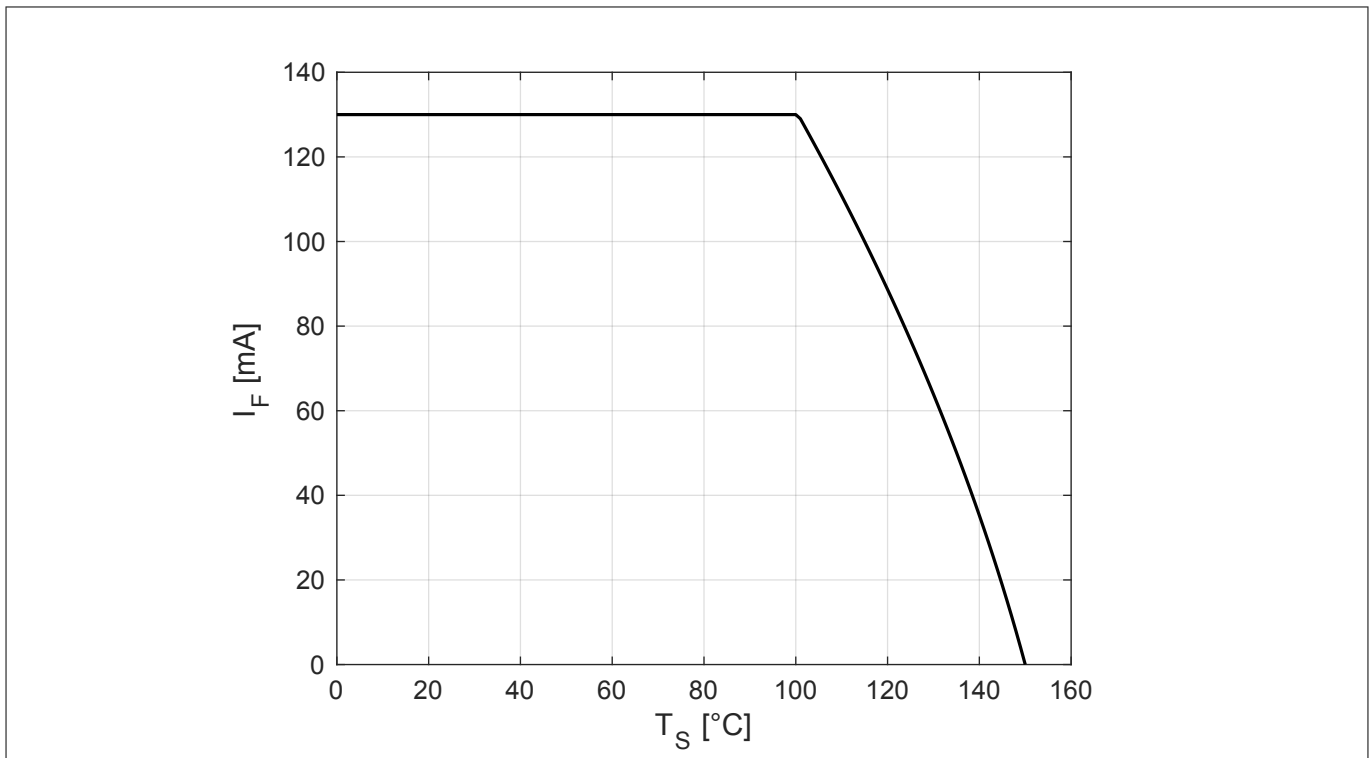


Figure 4 Permissible forward current I_F in DC operation

¹ For R_{thJS} in other conditions refer to the curves in this chapter.

Thermal characteristics

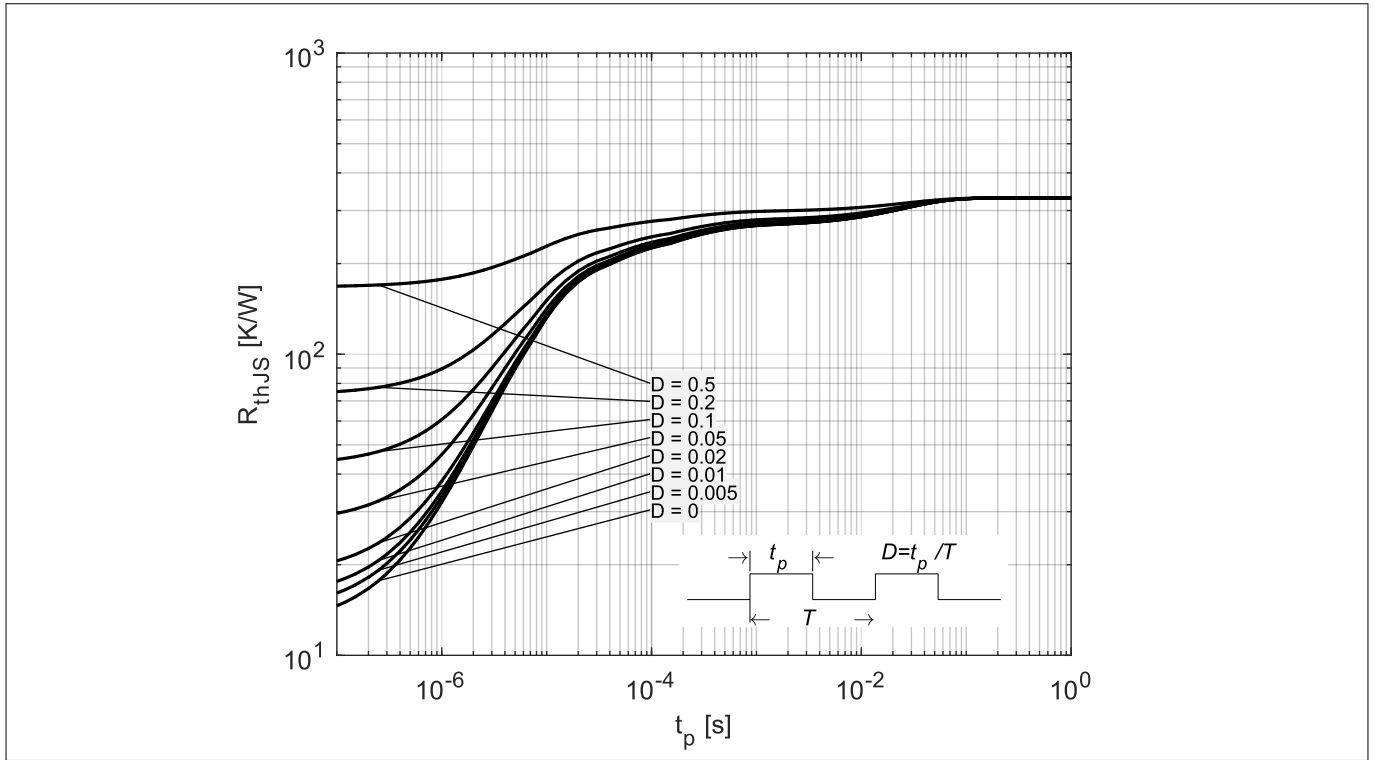


Figure 5 Thermal resistance R_{thJS} in pulse operation

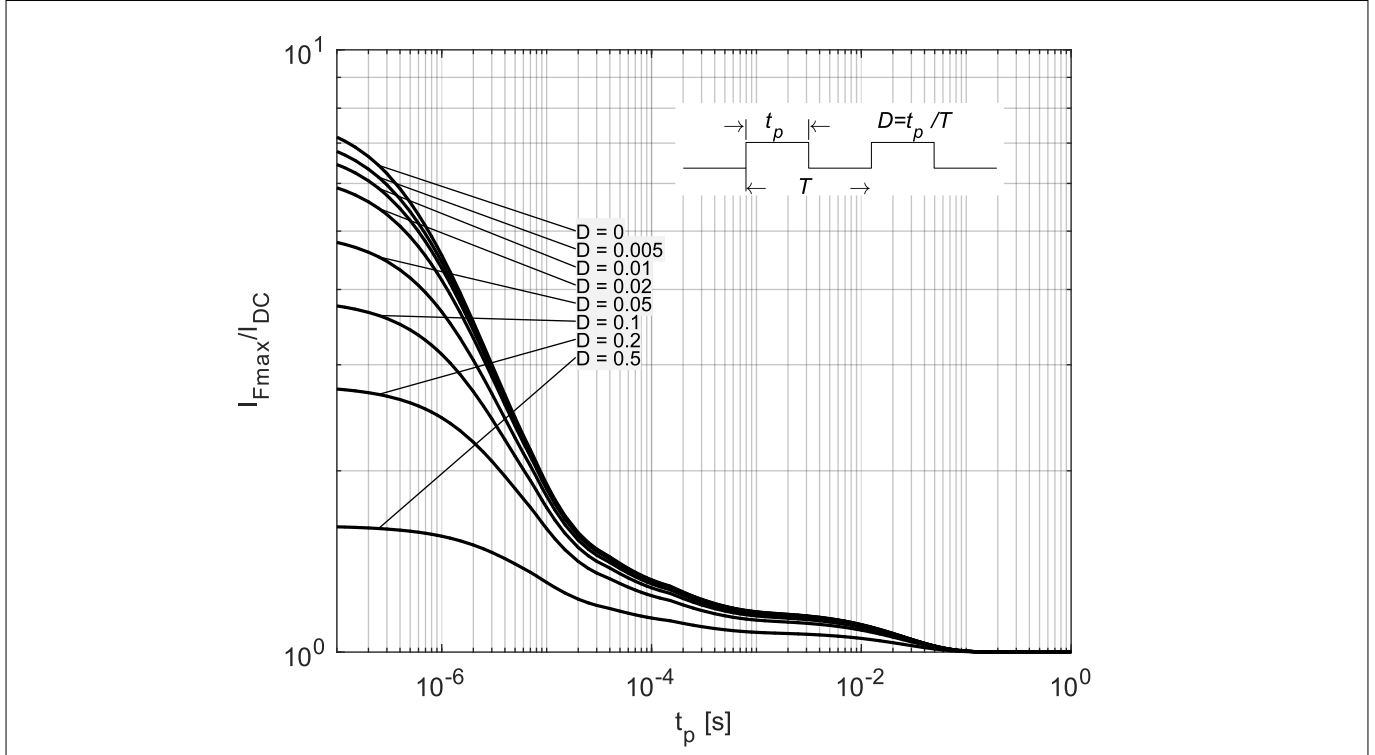


Figure 6 Permissible forward current ratio I_{Fmax}/I_{DC} in pulse operation

Package information SOT323-3

4 Package information SOT323-3

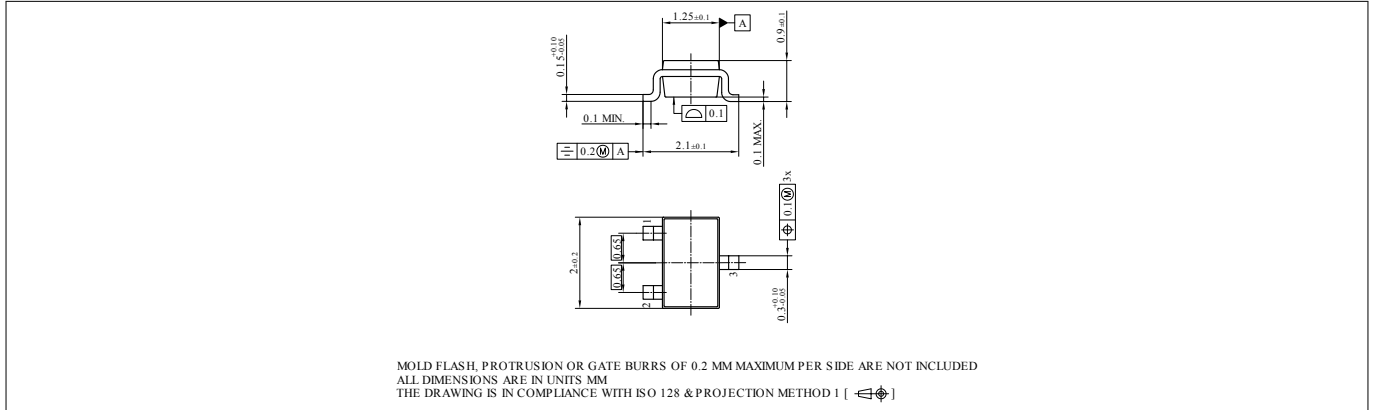


Figure 7 Package outline

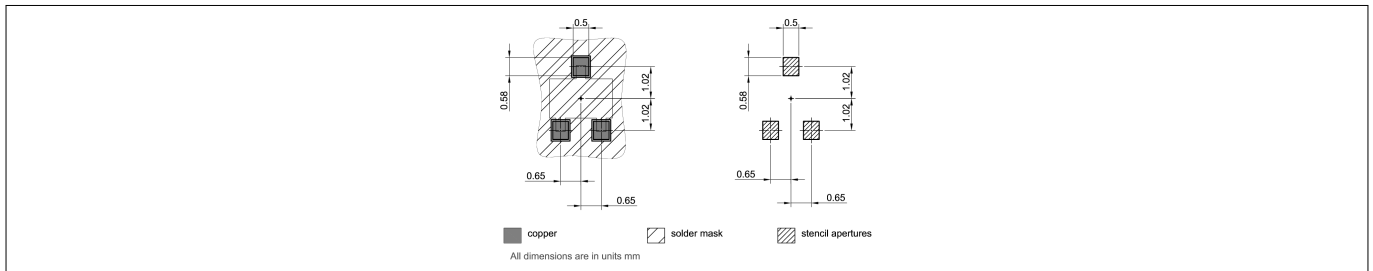


Figure 8 Foot print

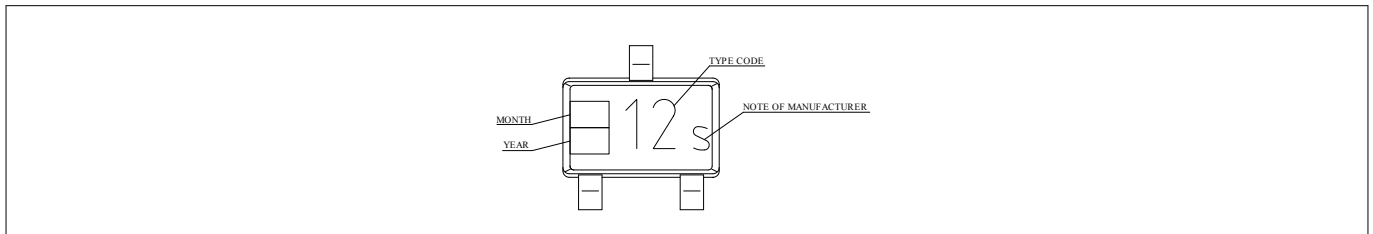


Figure 9 Marking layout example

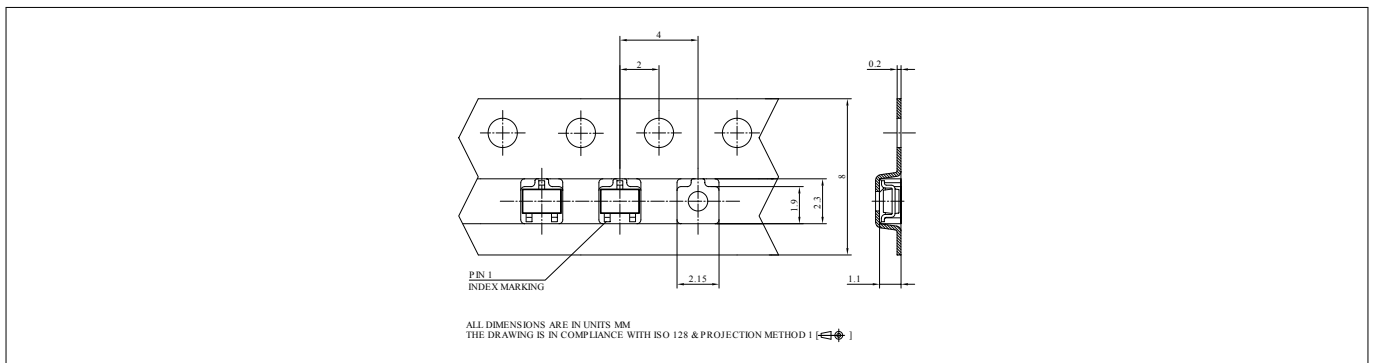


Figure 10 Tape information

Revision history

Revision history

Document version	Date of release	Description of changes
1.0	2018-09-07	<ul style="list-style-type: none">• Change from series datasheet to individual one• Initial release of datasheet• Typical values and curves updated to the values of the production (No product or process change behind)• Maximum values tightened (No product or process change behind)• Typical curves removed

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